NSN 5961-00-353-1239

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-353-1239 **Inclosure Material:** Plastic **Overall Length:** Between 0.660 inches and 0.780 inches **Terminal Length:** Between 0.115 inches and 0.210 inches **Overall Height:** 0.390 inches **Overall Width:** Between 0.290 inches and 0.310 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -40.0 collector to base voltage/static/emitter open all transistor and -40.0 collector to emitter voltage/static/base open all transistor and -5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 1.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 2000.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No